

Middle Power Class-D Speaker Amplifiers

Analog Input / BTL Output

Class-D Speaker Amplifier


BD5426MUV

No.10075EBT08

●Description

BD5426MUV is a 10W + 10W stereo class-D power amplifier IC, developed for space-saving and low heat-generation applications such as low-profile TV sets. The IC employs state-of-the-art Bipolar, CMOS, and DMOS (BCD) process technology that eliminates turn-on resistance in the output power stage and internal loss due to line resistances up to an ultimate level. With this technology, the IC has achieved high efficiency of 87% (9W + 9W output with 8Ω load), which is the top class in the industry. The IC, in addition, employs a compact back-surface heat radiation type power package to achieve low power consumption and low heat generation and eliminates necessity of installing an external radiator, up to a total output of 20W. This product satisfies both needs for drastic downsizing, low-profile structures and powerful, high-quality playback of the sound system.

●Features

- 1) A high efficiency of 87% (9W + 9W output with 8Ω load), which is the highest grade in the industry and low heat-generation.
- 2) An output of 10W + 10W (13V, with 8Ω load) is allowed without an external heat radiator.
- 3) Driving a lowest rating load of 6Ω is allowed.
- 4) Pop noise upon turning power on/off and power interruption has been reduced.
- 5) High-quality audio muting is implemented by soft-switching technology.
- 6) An output power limiter function limits excessive output to speakers.
- 7) High-reliability design provided with built-in protection circuits against high temperatures, against VCC shorting and GND shorting, against reduced-voltage, and against applying DC voltage to speaker.
- 8) A master/slave function allowing synchronization of multiple devices reduces beat noises.
- 9) Adjustment of internal PWM sampling clock frequencies (250 kHz to 400kHz) allows easy protective measures against unwanted radio emission to AM radio band.
- 10) A compact back-surface heat radiation type power package is employed.
VQFN048V7070 7.0mm × 7.0mm × 1.0mm, pitch 0.5mm

●Absolute maximum ratings

A circuit must be designed and evaluated not to exceed absolute maximum rating in any cases and even momentarily, to prevent reduction in functional performances and thermal destruction of a semiconductor product and secure useful life and reliability. The following values assume $T_a = 25^\circ\text{C}$. For latest values, refer to delivery specifications.

Parameter	Symbol	Ratings	Unit	Conditions
Supply voltage	VCC	+20	V	Pin 2, 14, 15, 22, 23, 38, 39, 46, 47 (Note 1, 2)
Power dissipation	Pd	3.28	W	(Note 3)
		4.8	W	(Note 4)
Input voltage for signal pin	VIN	-0.2 ~ +7.2	V	Pin 6, 7 (Note 1)
Input voltage for control pin	VCONT	-0.2 ~ Vcc+0.2	V	Pin 28, 32 (Note 1)
Input voltage for clock pin	VOSC	-0.2 ~ +7.2	V	Pin 31 (Note 1)
Operating temperature range	Topr	-40 ~ +85	°C	
Storage temperature range	Tstg	-55 ~ +150	°C	
Maximum junction temperature	Tjmax	+150	°C	

(Note 1) A voltage that can be applied with reference to GND (pins 5, 18, 19, 42, and 43)

(Note 2) Pd and $T_{jmax} = 150^\circ\text{C}$ must not be exceeded.

(Note 3) 114.3mm × 76.2mm × 1.6mm FR4 2-layer glass epoxy board (Copper Area 5505mm²) installed.

If used under $T_a = 25^\circ\text{C}$ or higher, reduce 26.2mW for increase of every 1°C. The board is provided with thermal via.

(Note 4) 114.3mm × 76.2mm × 1.6mm FR4 4-layer glass epoxy board (Copper Area 5505mm²) installed.

If used under $T_a = 25^\circ\text{C}$ or higher, reduce 38.4mW for increase of every 1°C. The board is provided with thermal via.

●Operating conditions

The following values assume $T_a = 25^\circ\text{C}$. Check for latest values in delivery specifications.

Parameter	Symbol	Ratings	Unit	Conditions
Supply voltage	VCC	+10 ~ +16.5	V	Pin 2, 14, 15, 22, 23, 38, 39, 46, 47
Load resistance	RL	6 ~ 16	Ω	(Note 5)

(Note 5) Pd should not be exceeded.

●Electrical characteristics

Except otherwise specified $T_a = 25^\circ\text{C}$, VCC = 12V, f_{IN} = 1kHz, R_g = 0 Ω , RL = 8 Ω , MUTEX="H", MS="L"

For latest values, refer to delivery specifications.

Parameter	Symbol	Limits	Unit	Conditions
Whole circuit				
Circuit current 1 (Sampling mode)	ICC1	25	mA	With no signal
Circuit current 2 (Muting mode)	ICC2	10	mA	MUTEX = "L"
Control circuit				
"H" level input voltage	V _{IH}	2.3 ~ 12	V	SDX, MUTEX, MS
"L" level input voltage	V _{IL}	0 ~ 0.8	V	SDX, MUTEX, MS
Audio circuit				
Voltage gain	G _V	28	dB	P _o = 1W
Maximum output power 1 (Note 6)	PO1	9	W	THD+N = 10%
Maximum output power 2 (Note 6)	PO2	10	W	V _{cc} =13V, THD+N = 10%
Total harmonic distortion (Note 6)	THD	0.1	%	P _o = 1W, BW=20Hz ~ 20kHz
Crosstalk	CT	85	dB	P _o = 1W, R _g = 0 Ω , BW = IHF-A
Output noise voltage (Sampling mode)	VNO	80	μVrms	R _g = 0 Ω , BW = IHF-A
Residual noise voltage (Muting mode)	VNOM	1	μVrms	R _g = 0 Ω , BW = IHF-A, MUTEX = "L"
Internal sampling clock frequency	FOSC	250	kHz	MS = "L" (In master operation)

(Note 6) The rated values of items above indicate average performances of the device, which largely depend on circuit layouts, components, and power supplies. The reference values are those applicable to the device and components directly installed on a board specified by us.

●Electrical characteristic curves (Reference data)

(1) Under Stereo Operation($R_L=8\Omega$)

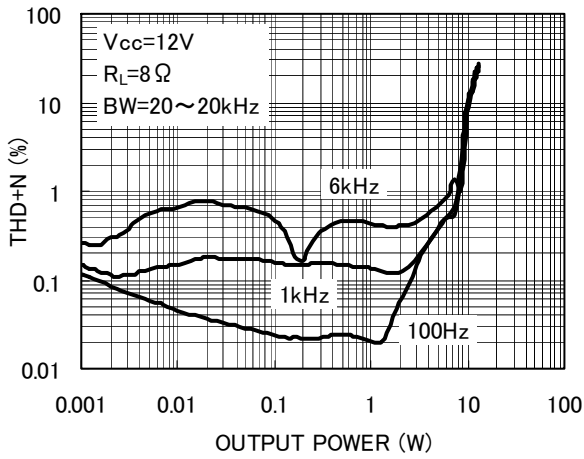


Fig. 1 THD+N - Output power

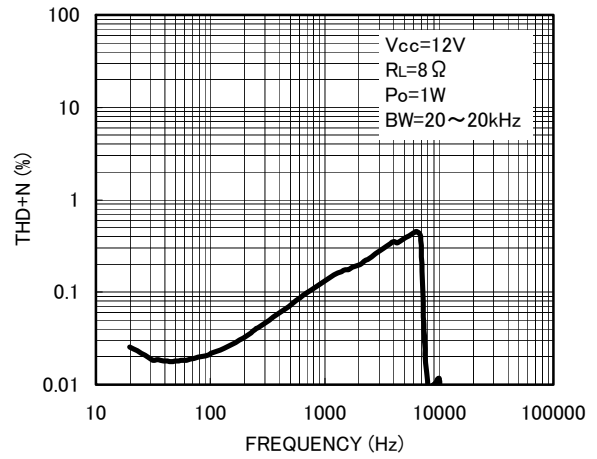


Fig. 2 THD+N - Frequency

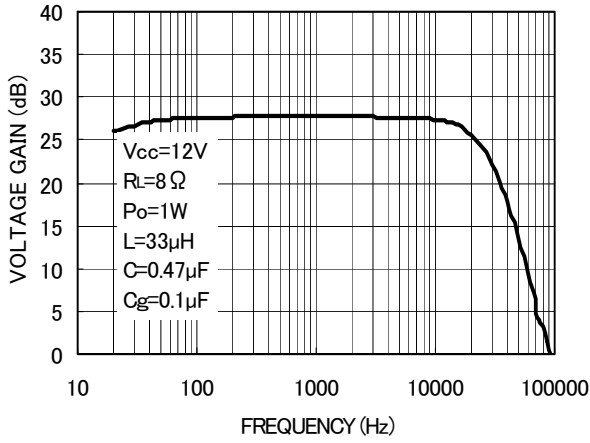


Fig. 3 Voltage gain - Frequency

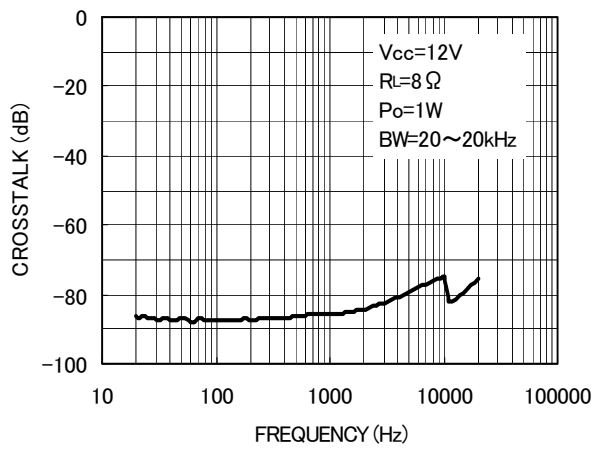


Fig. 4 Crosstalk - Frequency

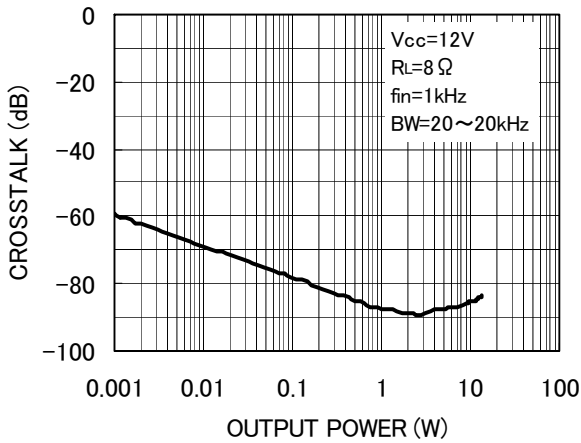


Fig. 5 Crosstalk - Output power

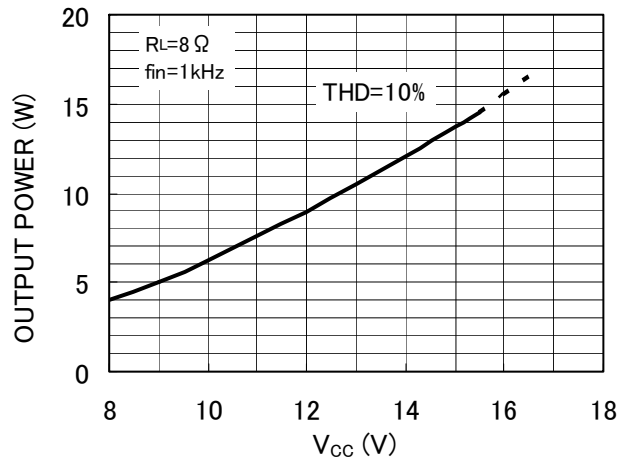


Fig. 6 Output power - Power supply voltage

●Electrical characteristic curves (Reference data) – Continued

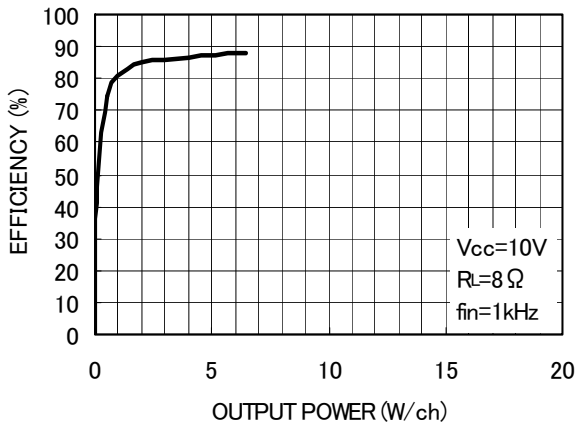


Fig. 7 Efficiency - Output power

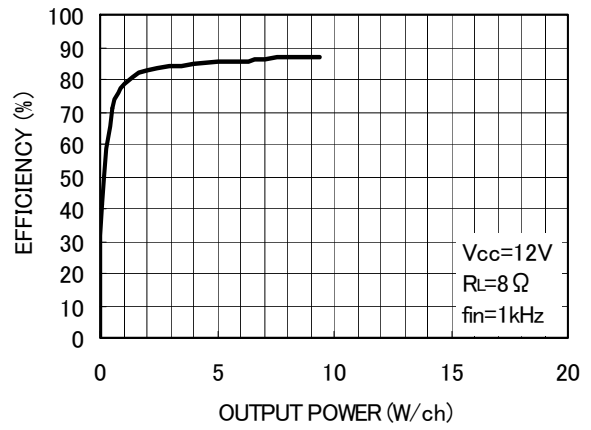


Fig. 8 Efficiency - Output power

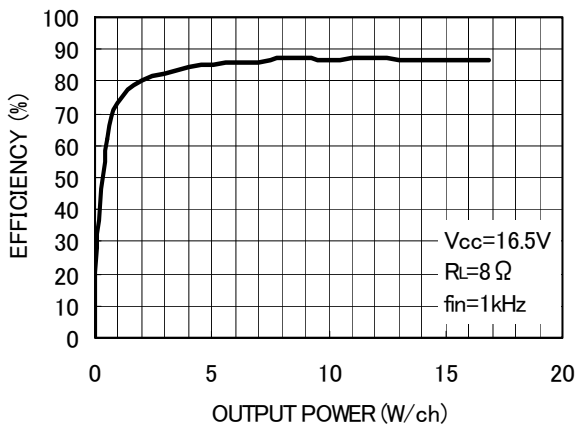


Fig. 9 Efficiency - Output power

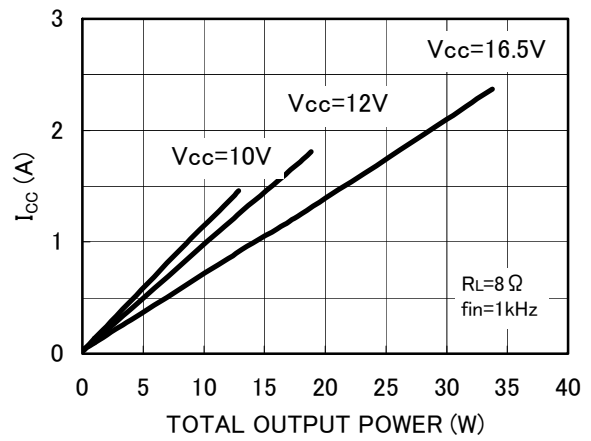


Fig. 10 Current consumption - Output power

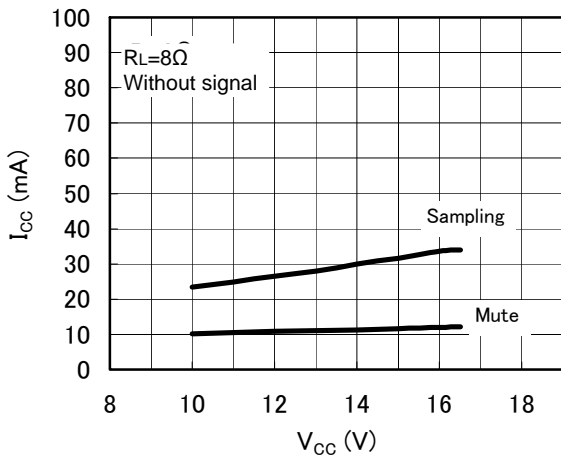


Fig. 11 Current consumption - Power supply voltage

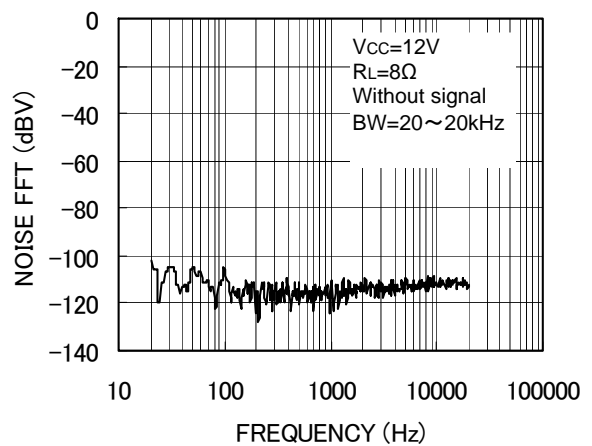


Fig. 12 FFT of Output Noise Voltage

●Electrical characteristic curves (Reference data) – Continued

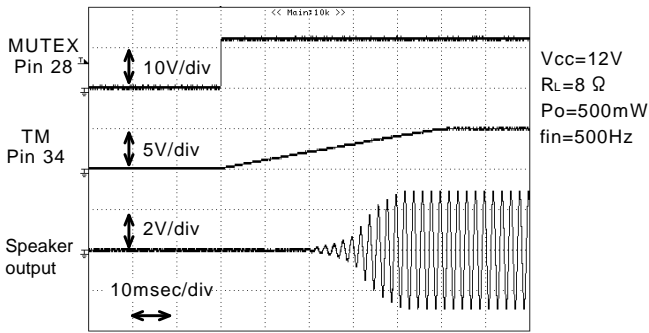


Fig. 13 Wave form when Releasing Soft-mute

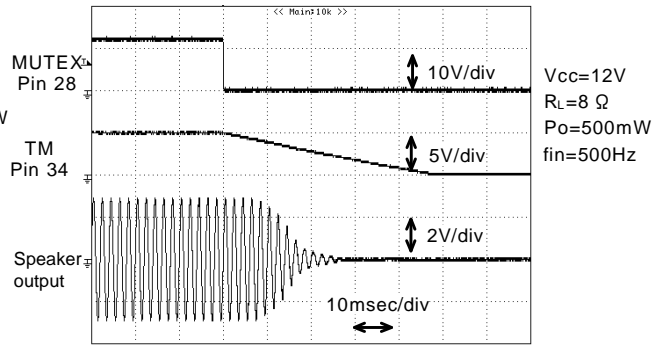


Fig. 14 Wave form when Activating Soft-mute

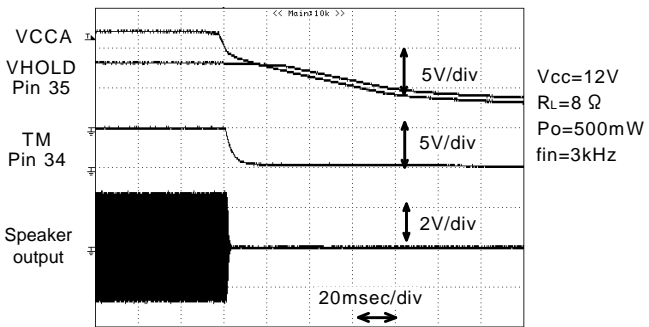


Fig. 15 Wave form on Instantaneous Power Interruption(20msec / div)

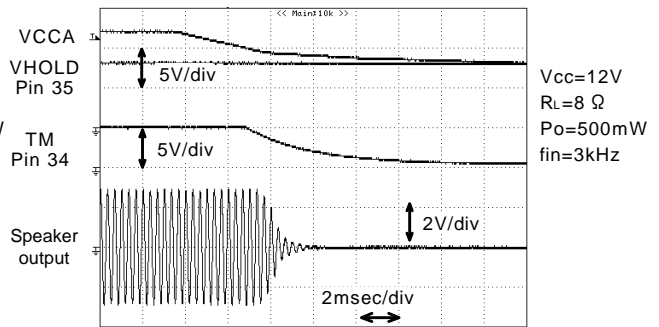


Fig. 16 Wave form on Instantaneous Power Interruption(2msec / div)

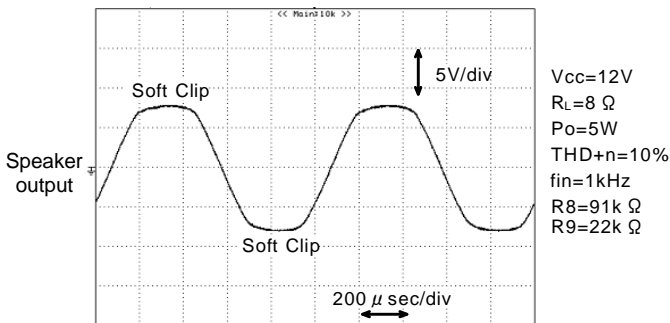


Fig. 17 Wave form on Output Power Limiter function (Po = 5W)

●Electrical characteristic curves (Reference data) – Continued

(2) Under Stereo Operation($R_L=6\Omega$)

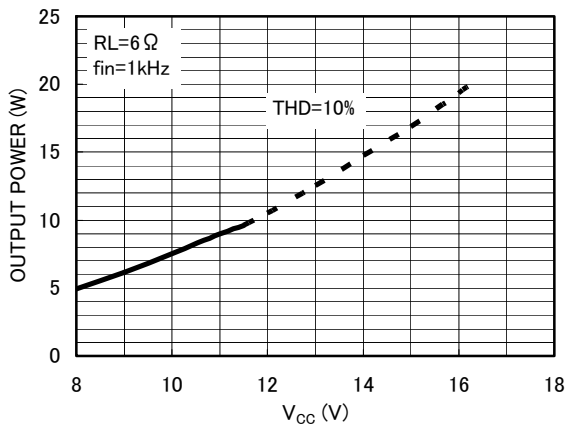


Fig. 18 Output power - Power supply voltage

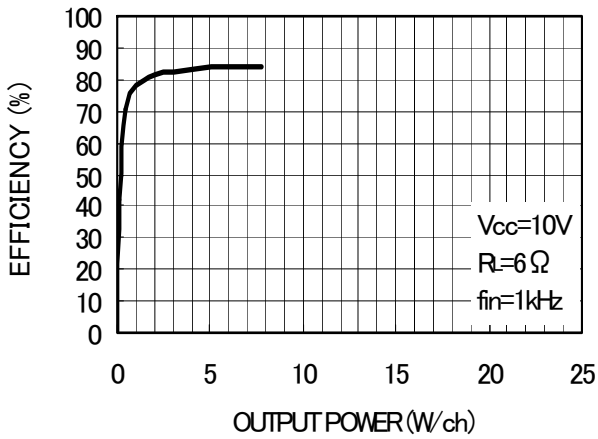


Fig. 19 Efficiency - Output power

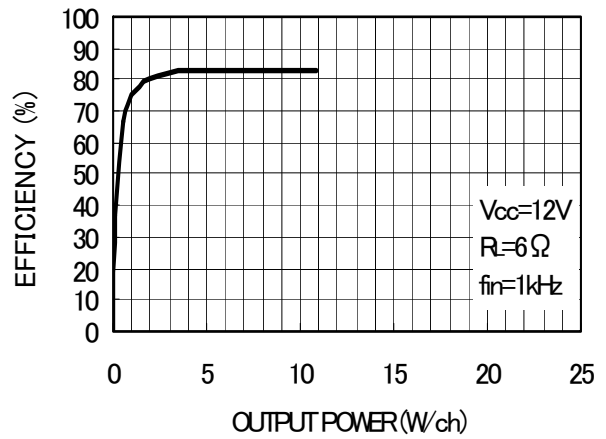


Fig. 20 Efficiency - Output power

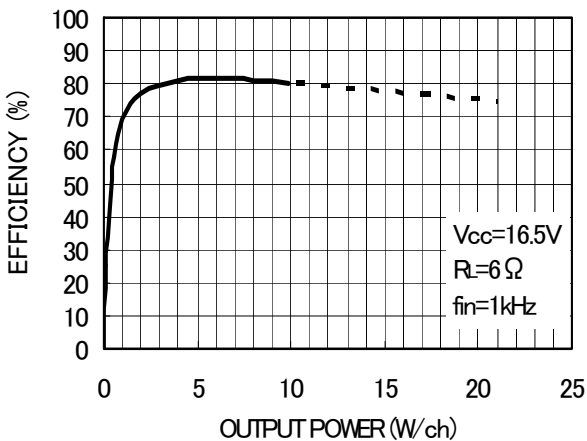


Fig. 21 Efficiency - Output power

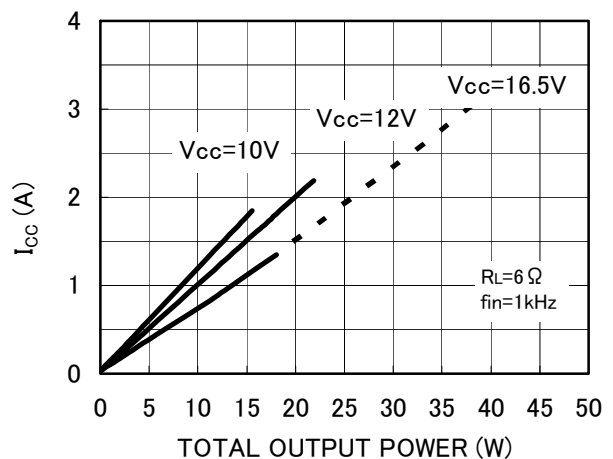


Fig. 22 Current consumption - Output power

Dotted lines of the graphs indicate continuous output power to be obtained on musical signal source or by installing additional heat sinks.

●Block diagram

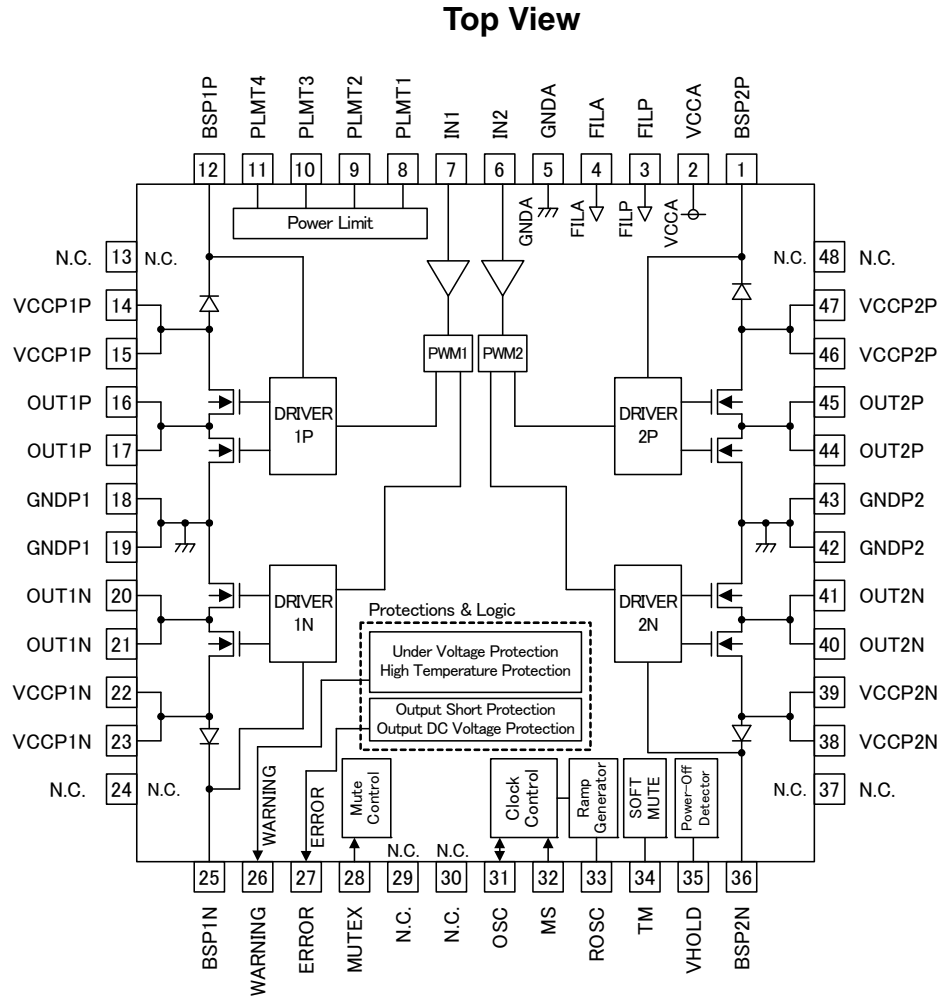


Fig. 23 Pin Assignment Diagram

●Outer Dimensions and Inscriptions

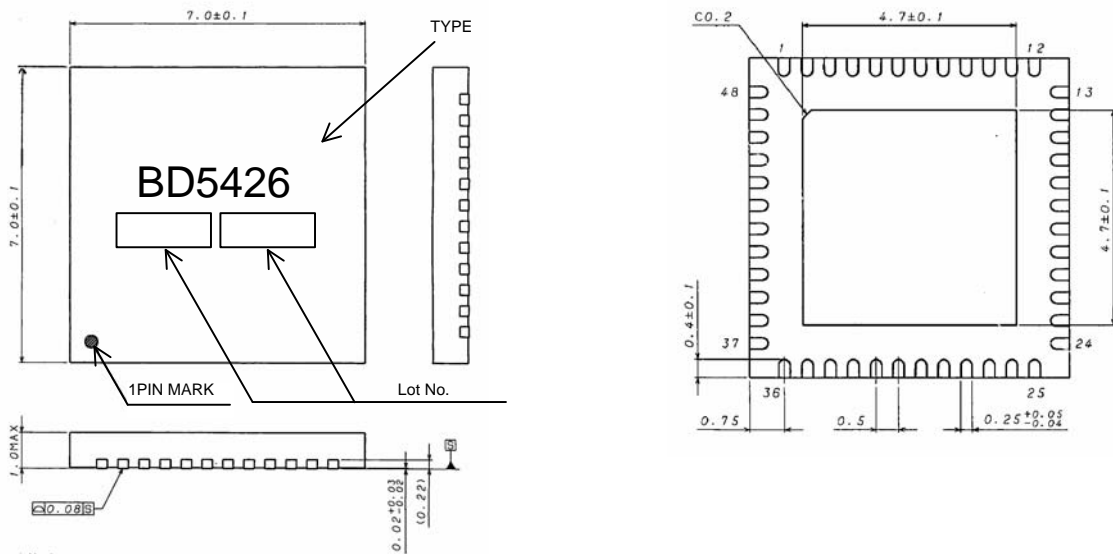
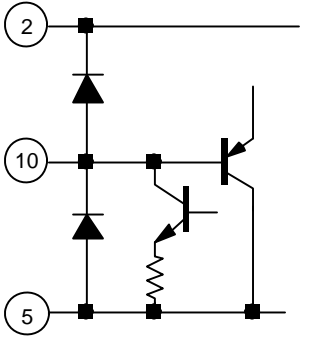
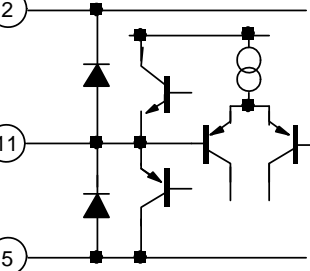
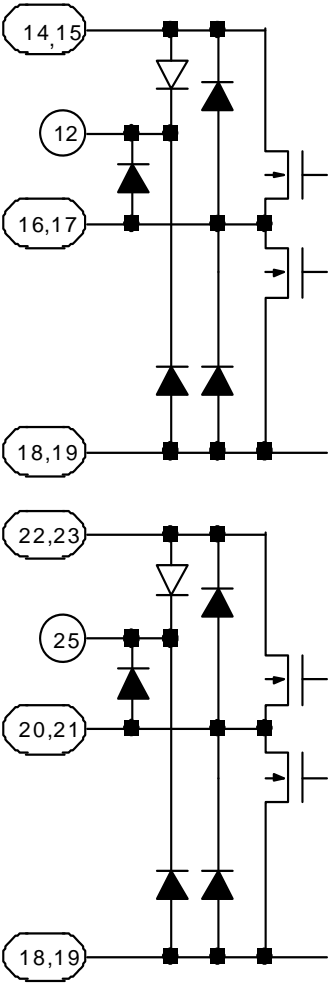


Fig. 24 Outer Dimensions and Inscriptions of VQFN048V7070 Package

●Explanation of Pin Functions (Provided pin voltages are typical values.)

No.	Symbol	Pin voltage	Pin description	Internal equalizing circuit
2	VCCA	Vcc	Analog system power pin	
3	FILP	$V_{cc} + \frac{35}{12}$	PWM system bias pin Connect a capacitor.	
4	FILA	3.5V	Analog signal system bias pin Connect a capacitor.	
5	GNDA	0V	Analog system GND pin	
6 7	IN2 IN1	3.5V	ch2 Analog signal input pin ch1 Analog signal input pin Input audio signal via a capacitor.	
8	PLMT1	3.5V	Voltage-to-current conversion pin for output power limiter function Connect a register.	
9	PLMT2	-	Current-to-voltage conversion pin for output power limiter function Connect a register.	

●Explanation of Pin Functions - Continued

No.	Symbol	Pin voltage	Pin description	Internal equalizing circuit
10	PLMT3	-	Current-to-voltage conversion pin for output power limiter function Connect a register.	
11	PLMT4	3.5V	Bias pin for output power limiter function Connect a register and a capacitor.	
12	BSP1P	-	ch1 positive bootstrap pin Connect a capacitor.	
14, 15	VCCP1P	Vcc	ch1 positive power system power supply pin	
16, 17	OUT1P	Vcc ~ 0V	ch1 positive PWM signal output pin Connect with output LPF.	
18, 19	GNDP1	0V	ch1 power system GND pin	
20, 21	OUT1N	Vcc ~ 0V	ch1 negative PWM signal output pin Connect with output LPF.	
22, 23	VCCP1N	Vcc	ch1 negative power system power supply pin	
25	BSP1N	-	ch1 negative bootstrap pin Connect a capacitor	

●Explanation of Pin Functions - Continued

No.	Symbol	Pin voltage	Pin description	Internal equalizing circuit
26	WARNING	H: 5V L: 0V	Warning output pin Pin to notify operation warning. H: Under warning L: Normal operation Connect a resistor.	
27	ERROR	H: 5V L: 0V	Error output pin A pin for notifying operation errors. H: Error L: Normal operation Connect a resistor.	
28	MUTEX	-	Audio mute control pin H: Mute off L: Mute on	
13, 24 29, 30 37, 48	N.C.	-	N.C. pin Nothing is connected with IC internal circuit.	
31	OSC	-	Sampling clock signal input/output pin When using two or more sampling clocks, connect via a capacitor.	
32	MS	-	Master/Slave switching pin Switching of master/slave functions on a sampling clock signal. H: Slave operation L: Master operation	

●Explanation of Pin Functions - Continued

No.	Symbol	Pin voltage	Pin description	Internal equalizing circuit
33	ROSC	5.6V	Internal PWM sampling clock frequency setting pin Usually the pin is used open. To adjust an internal sampling clock frequency, connect a resistor.	
34	TM	0 ~ 5V	Audio muting constant setting pin Connect a capacitor.	
35	VHOLD	0.68xVcc	Instantaneous power interruption detecting voltage setting pin Connect a capacitor. To adjust a detecting voltage, connect a resistor.	
36	BSP2N	-	ch2 negative bootstrap pin Connect a capacitor.	
38, 39	VCCP2N	Vcc	ch2 negative power system power supply pin	
40, 41	OUT2N	Vcc ~ 0V	ch2 negative PWM signal output pin Connect an output LPF.	
42, 43	GNDP2	0V	cch2 power system GND pin	
44, 45	OUT2P	Vcc ~ 0V	ch2 positive PWM signal output pin Connect an output LPF.	
46, 47	VCCP2P	Vcc	ch2 positive power system power supply pin	
1	BSP2P	-	ch2 positive bootstrap pin Connect a capacitor.	

● Application Circuit Diagram

• Vcc=10V ~ 16.5V

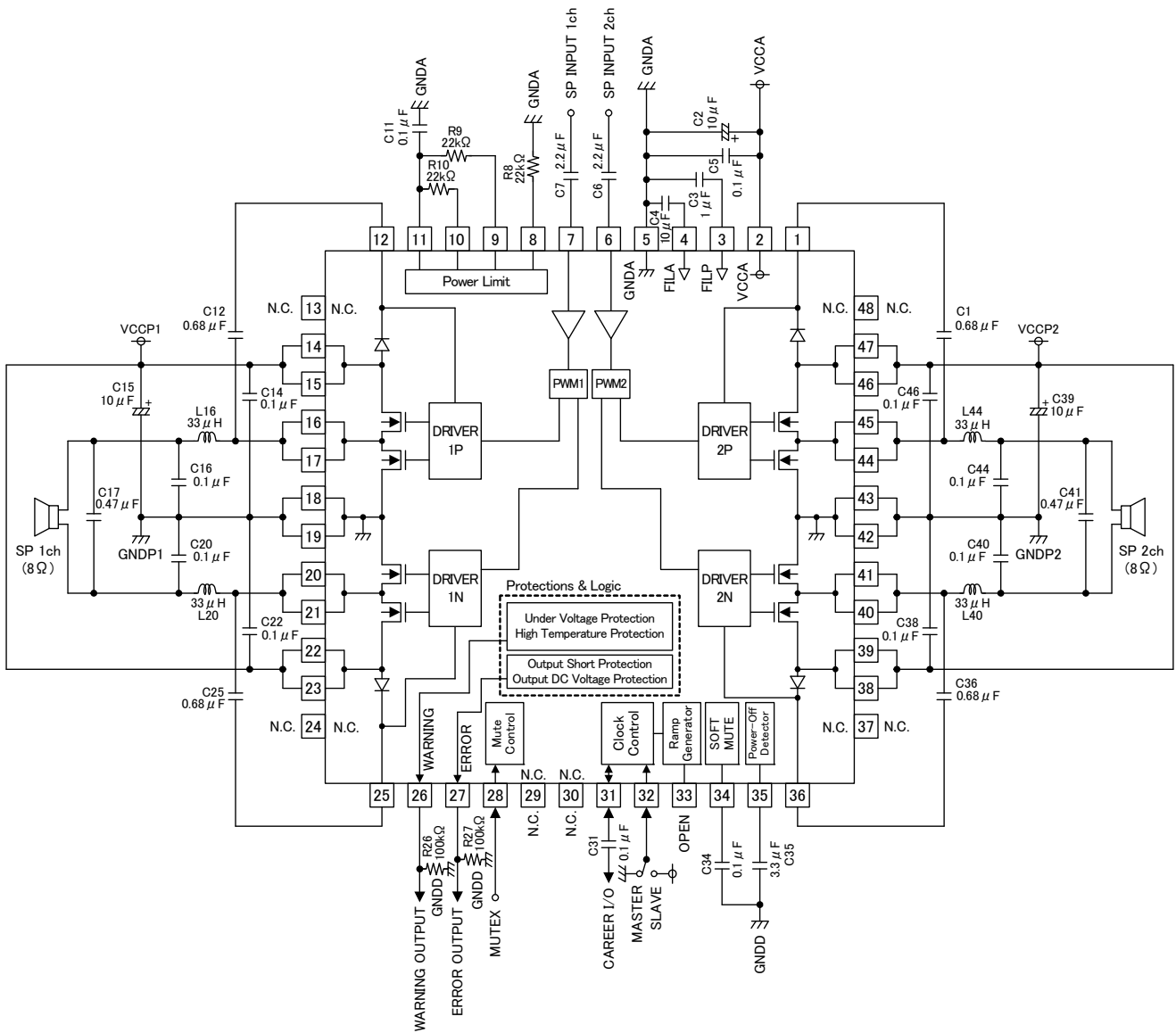


Fig. 25 Circuit Diagram of Stereo Operation with 8Ω Load

Table 1 BOM List of Stereo Operation with 8Ω Load

No.	Item	Part Number	Vendor	Configuration		Value	Rated voltage	Tolerance	Temperature characteristics	Quantity	Reference
				mm	inch						
1	IC	BD5426MUV	ROHM	VQFN048V7070		-	-	-	-	1	IC1
2	C	GRM219B31E684KA88	MURATA	2012	0805	0.68μF	25V	±10%	±10%	4	C1, C12, C25, C36
3	C	GRM188R11H104KA93	MURATA	1608	0603	0.1μF	50V	±10%	±15%	5	C5, C14, C22, C38, C46
4	C	GRM21BB11H104KA01	MURATA	2012	0805	0.1μF	50V	±10%	±10%	4	C16, C20, C40, C44
5	C	25ST225M3216	Rubycon	3225	1210	2.2μF	25V	±20%	±5%	2	C6, C7
6	C	50ST474M3225	Rubycon	3225	1210	0.47μF	50V	±20%	±5%	2	C17, C41
7	C	GRM21BB31E335KA75	MURATA	2012	0805	3.3μF	25V	±10%	±10%	1	C35
8	C	GRM188B11E104KA01	MURATA	1608	0603	0.1μF	25V	±10%	±10%	3	C11, C31, C34
9	C	GRM21BB11C105KA01	MURATA	2012	0805	1μF	16V	±10%	±10%	1	C3
10	C	GRM21BB31C106KE15	MURATA	2012	0805	10μF	16V	±10%	±10%	1	C4
11	C	25SVPD10M	SANYO	6666	2626	10μF	25V	±20%	±25%	3	C2, C15, C39
12	R	MCR01MZPF2202	ROHM	1005	0402	22kΩ	50V	±1%	±200ppm/°C	3	R8, R9, R10
13	R	MCR01MZPF1003	ROHM	1005	0402	100kΩ	50V	±1%	±200ppm/°C	2	R26, R27

No.	Item	Part Number	Vendor	Configuration	Value	Tolerance	DC Resistance	Rated DC Current	Quantity	Reference
				mm						
14	L	7G09B-330M	SAGAMI	10×9×10	33μH×2	±20%	44mΩmax.	4.1A max.	2	L16, L20, L40, L44

●Notes for use

1. About absolute maximum ratings

If an applied voltage or an operating temperature exceeds an absolute maximum rating, it may cause destruction of a device. A result of destruction, whether it is short mode or open mode, is not predictable. Therefore, provide a physical safety measure such as fuse, against a special mode that may violate conditions of absolute maximum ratings.

2. About power supply line

As return of current regenerated by back EMF of output coil happens, take steps such as putting capacitor between power supply and GND as a electric pathway for the regenerated current. Be sure that there is no problem with each property such as emptied capacity at lower temperature regarding electrolytic capacitor to decide capacity value. If the connected power supply does not have sufficient current absorption capacity, regenerative current will cause the voltage on the power supply line to rise, which combined with the product and its peripheral circuitry may exceed the absolute maximum ratings. It is recommended to implement a physical safety measure such as the insertion of a voltage clamp diode between the power supply and GND pins.

3. Potential of GND (5, 18, 39, 42, and 43 pins)

Potential of the GND terminal must be the lowest under any operating conditions.

4. About thermal design

Perform thermal design with sufficient margins, in consideration of maximum power dissipation Pd under actual operating conditions. This product has an exposed frame on the back of the package, and it is assumed that the frame is used with measures to improve efficiency of heat dissipation. In addition to front surface of board, provide a heat dissipation pattern as widely as possible on the back also.

A class-D power amplifier has heat dissipation efficiency far higher than that of conventional analog power amplifier and generates less heat. However, extra attention must be paid in thermal design so that a power dissipation Pdiss should not exceed the maximum power dissipation Pd.

$$\text{Maximum power dissipation} \quad P_d = \frac{T_{j\max} - T_a}{\theta_{ja}} \quad [\text{W}]$$

$$\text{Power dissipation} \quad P_{\text{diss}} = P_o \left(\frac{1}{\eta} - 1 \right) \quad [\text{W}]$$

Tjmax: Maximum temperature junction = 150[°C]

Ta: Operating ambient temperature [°C]

θja: Package thermal resistance [°C/W]

Po: Output power [W]

η: Efficiency

5. About operations in strong electric field

Note that the device may malfunction in a strong electric field.

6. Thermal shutdown (TSD) circuit

This product is provided with a built-in thermal shutdown circuit. When the thermal shutdown circuit operates, the output transistors are placed under open status. The thermal shutdown circuit is primarily intended to shut down the IC avoiding thermal runaway under abnormal conditions with a chip temperature exceeding Tjmax = 150°C, and is not intended to protect and secure an electrical appliance. Accordingly, do not use this circuit function to protect a customer's electrical appliance.

7. About shorting between pins and installation failure

Be careful about direction and displacement of an IC when installing it onto the board. Faulty installation may destroy the IC when the device is energized. In addition, a foreign matter getting in between IC pins, pins and power supply, and pins and GND may cause shorting and destruction of the IC.

8. About power supply startup and shutdown

When starting up a power supply, be sure to place the MUTEX pin (pin 28) at "L" level. When shutting down a power supply also, be sure to place the pin at "L" level. Those processes reduce pop noises generated upon turning on and off the power supply. In addition, all power supply pins must be started up and shut down at the same time.

9. About WARNING output pin (pin 26) and ERROR output pin (pin 27)

A WARNING flag is output from the WARNING output pin upon operation of the high-temperature protection function and under-voltage protection function. And an ERROR flag is output from the ERROR output pin upon operation of VCC/GND shorting protection function and speaker DC voltage applying protection function. These flags are the function which the condition of this product is shown in. The use which aimed at the protection except for this product is prohibition.

10. About N.C. pins (pins 13, 24, 29, 30, 37, and 48)

The N.C. (Non connection) pins are not connected with an internal circuit. Leave the pins open or connect them to GND.

●Ordering part number

B	D
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Part No

5	4	2	6
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Part No.

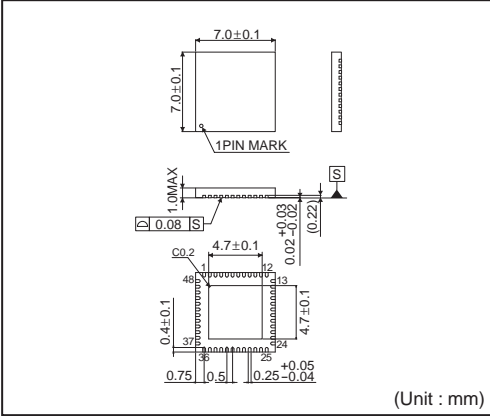
M	U	V
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Package
MUV: VQFN048V7070

E	2
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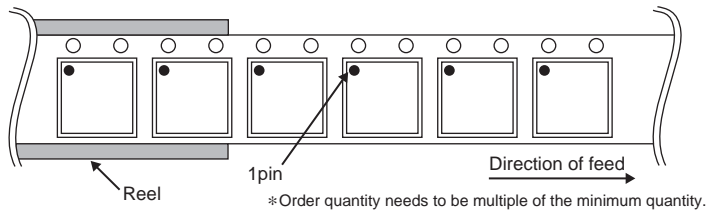
Packaging and forming specification
E2: Embossed tape and reel

VQFN048V7070



<Tape and Reel information>

Tape	Embossed carrier tape
Quantity	1500pcs
Direction of feed	E2 (The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand)



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The Products are not designed or manufactured to be used with any equipment, device or system which requires an extremely high level of reliability the failure or malfunction of which may result in a direct threat to human life or create a risk of human injury (such as a medical instrument, transportation equipment, aerospace machinery, nuclear-reactor controller, fuel-controller or other safety device). ROHM shall bear no responsibility in any way for use of any of the Products for the above special purposes. If a Product is intended to be used for any such special purpose, please contact a ROHM sales representative before purchasing.

If you intend to export or ship overseas any Product or technology specified herein that may be controlled under the Foreign Exchange and the Foreign Trade Law, you will be required to obtain a license or permit under the Law.



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ROHM Customer Support System

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Данный компонент на территории Российской Федерации

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Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

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